# **RoHS Compliant**

# Mini PCle Disk Module Plus

mPDM+ Product Specifications (Toshiba 15nm)

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Version 1.3



#### Apacer Technology Inc.

1F, No.32, Zhongcheng Rd., Tucheng Dist., New Taipei City, Taiwan, R.O.C Tel: +886-2-2267-8000 Fax: +886-2-2267-2261 www.apacer.com

# PCI-Express SSD APPxxxG2XB-AXX



## **Features:**

#### • Standard PCI Express Bus Interface

- PCI Express Specification Rev.2.0\*
- PCI Express Card Electromechanical Rev.
   2.0
- Supports ECRC (end-to-end CRC) and advanced error reporting
- Supports Spread Spectrum Clocking (SSC)

#### Capacity

- 8, 16, 32, 64, 128 GB

#### Performance\*\*

- Sustain Read Speed up to 370 MB/s
- Sustain Write Speed up to 185 MB/s

#### • Flash Management

- Supports ECC up to 72 bit correction per 1K Byte data
- Wear leveling
- Flash bad-block management
- S.M.A.R.T.
- Power Failure Management
- ATA Secure Erase

#### NAND Flash: MLC

#### Temperature Range

- Operating: 0 to 70°C
- Storage: -40°C to 85°C

#### Supply Voltage

- 3.3 V  $\pm$  5%

#### Power Consumption\*\*

Active mode: 675 mAIdle mode: 355 mA

#### Form Factor

- PCI Express Full-Mini Card Type
- Dimensions: 50.80 x 29.85 x 4.20, unit: mm

#### Connector Type

- One lane mini PCI Express
- RoHS Compliant
- Supports NCQ (Native Command Queue) Commands
- Supports AHCI 1.3

<sup>\*</sup>The mPDM+ is not backward compatible. Operational instability or inefficiency will occur if this device is applied on a PCIe 1.0 socket.

<sup>\*\*</sup>The performance and power consumption values addressed here are typical and may vary from platforms.

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# 1. General Description

Apacer's mPDM+ (mini PCIe Disk Module Plus) SSD offers a breakthrough in non-volatile memory storage. Formed as a mini PCI-Express card, this mPDM+ can fit in various types of embedded platforms, such as workstation, thin computing devices and high-end heavy duty servers where spaces are concerned. Regarding data transfer rate, mPDM+ delivers ideal data read/write performance.

Apacer mPDM+ provides one-lane PCI-Express 2.0 host interface, and is compatible with 5.0 Gbps maximum transfer rate. Compatibility wise, this mini PCIe SSD is not only fully compliant with PCI Express Specification Rev.2.0 and Electromechanical Rev.2.0, but also supports NCQ commands and IDE/AHCI operational modes.

## 1.1 Error Correction/Detection

The ECC engine in this device can detect and correct up to 72 bits error in 1K bytes.

## 1.2 Flash Block Management

Bad blocks are blocks that include one or more invalid bits, and their reliability is not guaranteed. Blocks that are identified and marked as bad by the manufacturer are referred to as "Initial Bad Blocks". Bad blocks that are developed during the lifespan of the flash are named "Later Bad Blocks". Thus, this device implements an efficient bad block management algorithm to detect the factory-produced bad blocks and manages any bad blocks that appear with use. This practice further prevents data being stored into bad blocks and improves the data reliability.

## 1.3 Wear Leveling

NAND Flash devices can only undergo a limited number of program/erase cycles, and in most cases, the flash media are not used evenly. If some area get updated more frequently than others, the lifetime of the device would be reduced significantly. Thus, Wear Leveling technique is applied to extend the lifespan of NAND Flash by evenly distributing write and erase cycles across the media. Apacer provides advanced Wear Leveling algorithm, which can efficiently spread out the flash usage through the whole flash media area. Moreover, by implementing both dynamic and static Wear Leveling algorithms, the life expectancy of the NAND Flash is greatly improved.

## 1.4 Power Failure Management

Power Loss Protection is a mechanism to prevent data loss during unexpected power failure. DRAM is a volatile memory and frequently used as temporary cache or buffer between the controller and the NAND flash to improve the SSD performance. However, one major concern of the DRAM is that it is not able to keep data during power failure. Accordingly, the module applies the flushing mechanism which requests the controller to transfer data to the cache. For this flash module, SDR performs as a cache, and its sizes include 8MB or 32MB. Only when the data is fully committed to the NAND flash will the controller send acknowledgement to the host. Such implementation can prevent false-positive performance and the risk of power cycling issues.

Additionally, it is critical for a controller to shorten the time the in-flight data stays in the cache. Thus, the module applies an algorithm to reduce the amount of data resides in the cache to provide a better performance by allowing incoming data to only have a "pit stop" in the cache and then move to the NAND flash at once. If the flash is jammed due to particular file sizes (random 4K), the cache will be treated as

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an "organizer", consolidating incoming data into groups before written into the flash to improve write amplification.

In sum, with this power failure management, this module proves to provide the reliability required by consumer, industrial, and enterprise-level application.

#### 1.5 ATA Secure Erase

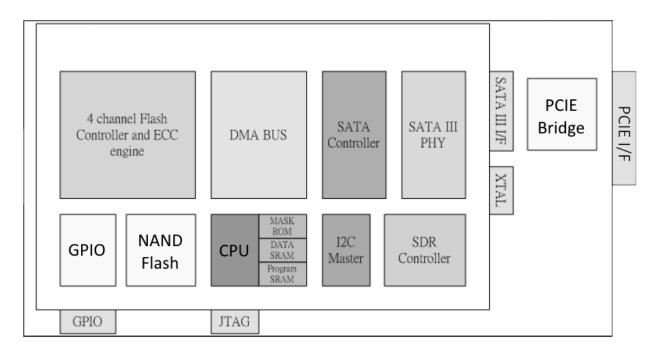
AATA Secure Erase is an ATA disk purging command currently embedded in most of the storage drives. Defined in ATA specifications, (ATA) Secure Erase is part of Security Feature Set that allows storage drives to erase all user data areas. The erase process usually runs on the firmware level as most of the ATA-based storage media currently in the market are built-in with this command. ATA Secure Erase can securely wipe out the user data in the drive and protects it from malicious attack.

### 1.6 S.M.A.R.T.

SMART, an acronym for Self-Monitoring, Analysis and Reporting Technology, is an open standard that allows a hard disk drive to automatically detect its health and report potential failures. When a failure is recorded by SMART, users can choose to replace the drive to prevent unexpected outage or data loss. Moreover, SMART can inform users of impending failures while there is still time to perform proactive actions, such as copy data to another device.

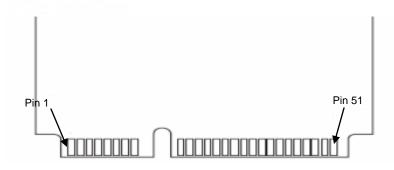


# 2. Block Diagram





# 3. Pin Assignments



Pin	Signal	Pin	Signal
51	Reserved	52	+3.3V
49	Reserved	50	GND
47	Reserved	48	Reserved
45	Reserved	46	Reserved
43	GND	44	Reserved
41	3.3V	42	Reserved
39	3.3V	40	Reserved
37	GND	38	NC
35	GND	36	NC
33	PETp0	34	GND
31	PETn0	32	Reserved
29	GND	30	Reserved
27	GND	28	NC
25	PERp0	26	GND
23	PERn0	24	+3.3Vaux
21	GND	22	PERST#
19	Reserved	20	Reserved
17	Reserved	18	GND
15	GND	16	NC
13	REFCLK+	14	NC
11	REFCLK-	12	NC
9	GND	10	NC
7	CLKREQ#	8	NC
5	NC	6	NC
3	NC	4	GND
1	Reserved	2	3.3V



# 4. Product Specifications

## 4.1 Capacity

Table 4-1 Capacity Specifications

Capacity	Total bytes*	Cylinders	Heads	Sectors	Max LBA
8 GB	8,012,390,400	15,525	16	63	15,649,200
16 GB	16,013,942,784	16,383	16	63	31,277,232
32 GB	32,017,047,552	16,383	16	63	62,533,296
64 GB	64,023,257,088	16,383	16	63	125,045,424
128 GB	128,035,676,160	16,383	16	63	250,069,680

<sup>\*</sup>Display of total bytes varies from file systems.

LBA count addressed in the table above indicates total user storage capacity and will remain the same throughout the lifespan of the device. However, the total usable capacity of the mPDM+ SSD is most likely to be less than the total physical capacity because a small portion of the capacity is reserved for device maintenance usages.

## 4.2 Performance

Performance and random read/write specifications of the mPDM+ are listed in following tables.

Table 4-2 Performance

Capacity Performance	8 GB	16 GB	32 GB	64 GB	128 GB
Sustained Read (MB/s)	150	265	345	370	360
Sustained Write (MB/s)	105	155	180	175	185

Note: Results may differ from various flash configurations or host system settings.

## 4.3 Environmental Specifications

Environmental specifications of mPDM+ product family follow the MIL-STD-810F standard.

Table 4-3 Environmental Specifications

Environment		Specifications
	Operation	0 to 70°C
Temperature	Storage	-40°C to 85°C
Vibration (Non-Operating)		Sine wave: 10~2000Hz, 15G (X, Y, Z axes)
Shock (Non-Operating)		Half sine wave, 1,500 G (X, Y, Z; All 6 axes)

<sup>\*\*</sup>Cylinders, heads or sectors are not applicable for these capacities. Only LBA addressing applies.



# 5. Electrical Specifications

**Caution: Absolute Maximum Stress Ratings –** Applied conditions greater than those listed under "Absolute Maximum Stress Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these conditions or conditions greater than those defined in the operational sections of this data sheet is not implied. Exposure to absolute maximum stress rating conditions may affect device reliability.

Table 5-1 Absolute Maximum Stress Ratings

Parameter	Min.	Typical	Max.	Units
Power supply	3.13	3.3	3.46	V
Operating temperature	0		70	°C
Storage temperature	-40		85	°C

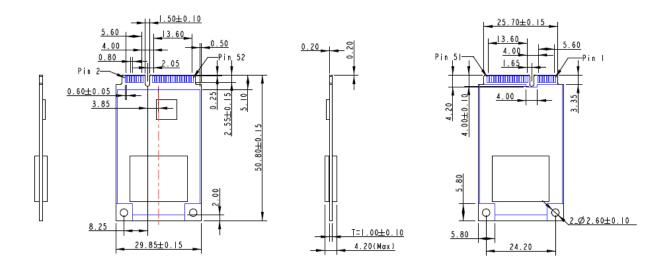
Table 5-2 Power Consumption (typical)

Capacity	8 GB	16 GB	32 GB	64 GB	128 GB
Active (mA)	525	585	620	620	675
Idle (mA)	350	355	350	340	340

<sup>\*</sup>Results may differ from various flash configurations and platforms.



# **6. Mechanical Specifications**



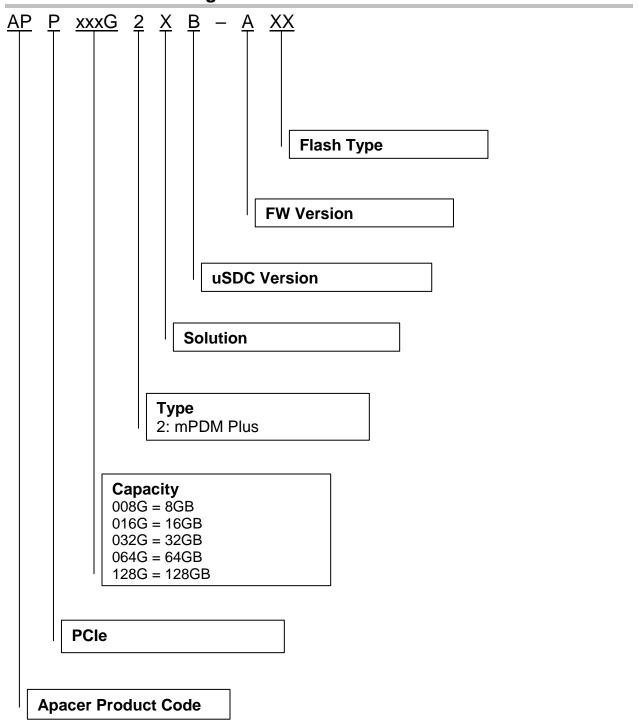
Unit: mm

Tolerance: ± 0.25



# 7. Product Ordering Information

# 7.1 Product Code Designations





## 7.2 Valid Combinations

Capacity	M/N
8GB	APP008G2DB-ATM
16GB	APP016G2DB-ATM
32GB	APP032G2DB-ATM
64GB	APP064G2DB-ATM
128GB	APP128G2DB-ATM

**Note:** Valid combinations are those products in mass production or will be in mass production. Consult your Apacer sales representative to confirm availability of valid combinations and to determine availability of new combinations.

Rev. 1.3



# **Revision History**

Revision	Date	Description	Remark
1.0	4/15/2016	Official release	
1.1	5/12/2016	Revised performance and power consumption values	
1.2	5/24/2016	<ul> <li>Updated performance and power consumption values for 128GB</li> <li>Revised product ordering information for 128GB and 256GB</li> </ul>	
1.3	12/29/2016	Removed 256GB support     Updated performance and power consumption values for 128GB	

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## **Global Presence**

Taiwan (Headquarters) Apacer Technology Inc.

1F., No.32, Zhongcheng Rd., Tucheng Dist.,

New Taipei City 236, Taiwan R.O.C.

Tel: 886-2-2267-8000 Fax: 886-2-2267-2261 amtsales@apacer.com

U.S.A. Apacer Memory America, Inc.

46732 Lakeview Blvd., Fremont, CA 94538

Tel: 1-408-518-8699 Fax: 1-510-249-9551 sa@apacerus.com

Japan Apacer Technology Corp.

5F, Matsura Bldg., Shiba, Minato-Ku

Tokyo, 105-0014, Japan Tel: 81-3-5419-2668 Fax: 81-3-5419-0018 ipservices@apacer.com

Europe Apacer Technology B.V.

Science Park Eindhoven 5051 5692 EB Son,

The Netherlands Tel: 31-40-267-0000 Fax: 31-40-290-0686 sales@apacer.nl

China Apacer Electronic (Shanghai) Co., Ltd

Room D, 22/FL, No.2, Lane 600, JieyunPlaza, Tianshan RD, Shanghai, 200051, China

Tel: 86-21-6228-9939 Fax: 86-21-6228-9936 sales@apacer.com.cn

India Apacer Technologies Pvt Ltd,

Unit No.201, "Brigade Corner", 7<sup>th</sup> Block Jayanagar,

Yediyur Circle, Bangalore - 560082, India

Tel: 91-80-4152-9061 Fax: 91-80-4170-0215 sales india@apacer.com